



MASWGM0003-DIE 903231 — Preliminary Information

#### **Features**

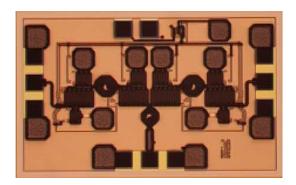
- ♦ 2.0-8.0 GHz Operation
- ◆ 3 dB Insertion Loss
- Non-Reflective
- ◆ TTL Control
- Excellent Match on Off Port
- ◆ MSAG™ Process

#### **Description**

The MASWGM0003-DIE is a single-pole, double-throw switch that is fully matched to 50 ohms on both the input and output.

Fabricated using M/A-COM's repeatable, high performance and highly reliable GaAs Multifunction Self-Aligned Gate (MSAG $^{\text{TM}}$ ) Process, each device is 100% RF tested on wafer to ensure performance compliance.

M/A-COM's MSAG™ process features robust silicon-like manufacturing processes, planar processing of ion implanted transistors, multiple implant capability enabling power, low-noise, switch and digital FETs on a single chip, and polyimide scratch protection for ease of use with automated manufacturing processes. The use of refractory metals and the absence of platinum in the gate metal formulation prevents hydrogen poisoning when employed in hermetic packaging.



### **Primary Applications**

- ◆ Test Equipment and Instrumentation
- ◆ Electronic Warfare
- Weather and Military Radar
- Point to Point Communications
- VSAT

# Electrical Characteristics: $T_B = 25^{\circ}C^1$ , $Z_0 = 50\Omega$ , $V_{EE} = -5V$

Parameter	Symbol	Typical	Units
Bandwidth	f	2.0-8.0	GHz
Insertion Loss @ 4 GHz	IL	1.6	dB
Insertion Loss @ 8 GHz	IL	3.0	dB
Isolation	ISO	> 45	dB
Input VSWR	VSWR	1.6:1	
Output VSWR (On)	VSWR	1.7:1	
Output VSWR (Off)	VSWR	1.7:1	
Input Third Order Intercept	ITOI	35	dBm
Input 1-dB Compression Point	P1dB	26	dBm

1. T<sub>B</sub> = MMIC Base Temperature

information.

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# **Maximum Operating Conditions** <sup>2</sup>

Parameter	Symbol	Absolute Maximum	Units
Input Power	P <sub>IN</sub>	31	dBm
Digital Driver Voltage	$V_{EE}$	-6.0	V
Junction Temperature	TJ	180	°C
Storage Temperature	T <sub>STG</sub>	-55 to +150	°C

Operation outside of these ranges may reduce product reliability. Operation at other than the typical values may result in performance outside the guaranteed limits.

### **Recommended Operating Conditions**

Characteristic	Symbol	Min	Тур	Max	Unit
Digital Driver Voltage	V <sub>EE</sub>	-5.2	-5	-4.8	V
Digital Driver Current	I <sub>EE</sub>	3	5	10	mA

## TTL Path Selection<sup>3</sup>

Characteristic	Logic Level (@ Pad A)	Min	Тур	Max	Unit
Com-Out1	Logic High	3.0	5.0	5.0	V
Com-Out2	Logic Low	0	0	0.4	V

<sup>3.</sup> Voltage Levels valid from  $-55^{\circ}$ C to  $+150^{\circ}$  Base Temperature for  $V_{EE}$ =-5V.

## **Operating Instructions**

This device is static and light sensitive. Digital circuitry operation can be impaired under high intensity light, e.g. microscope light. Please handle with care. To operate the device, follow these steps.

- 1. Power Up: Apply  $V_{EE} = -5 \text{ V}$ .
- 2. Apply Logic Voltages to control Circuits as listed in Recommended Operating Conditions
- 3. Power Down: Set  $V_{EE} = 0$



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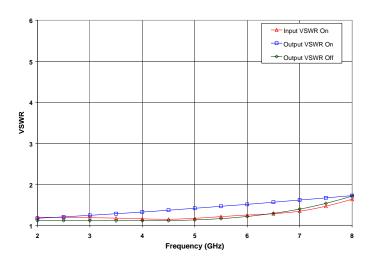


Figure 1. Input and Output VSWR vs. Frequency

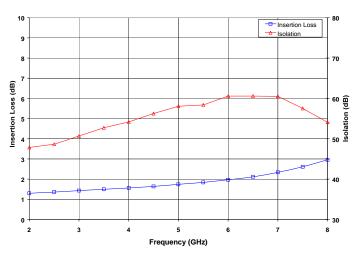


Figure 2. Insertion Loss and Isolation vs. Frequency

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#### **Mechanical Information**

Chip Size: 2.054 x 1.294 x 0.075 mm (81 x 51 x 3)

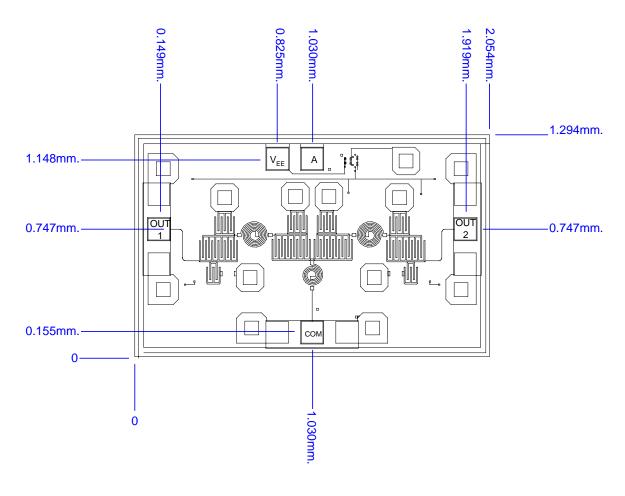


Figure 3. Die Layout

#### **Bond Pad Dimensions**

Pad	Size (μm)	Size (mils)
RF: COMMON, OUT1, OUT2	125 x 125	5 x 5
Digital Driver Voltage V <sub>EE</sub>	125 x 125	5 x 5
A (TTL Control)	125 x 125	5 x 5

<sup>4</sup> 

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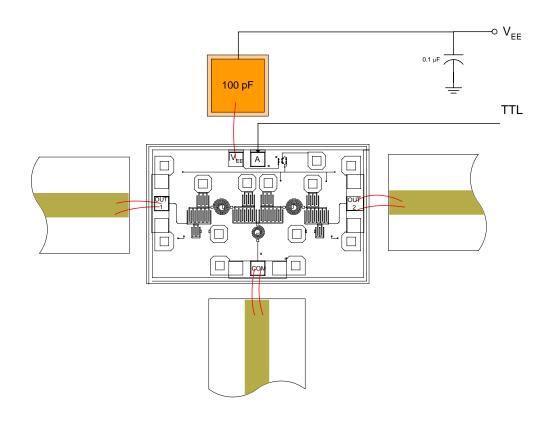
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#### **Assembly and Bonding Diagram**



**Figure 4. Recommended bonding diagram** for pedestal mount. Support circuitry typical of MMIC characterization.

# **Assembly Instructions:**

**Die attach:** Low thermal conductivity silver epoxies are acceptable for die attach of this MMIC. Follow the manufacturer's instructions. If solder is employed, use AuSn (80/20) 1 mil preform solder. Limit time @ 300 °C to less than 5 minutes.

**Wirebonding:** Bond @ 160 °C using standard ball or thermal compression wedge bond techniques. For DC and RF pad connections, use either ball or wedge bonds. For best performance, especially above 10 GHz, wedge bonds of shortest length employed on the RF interconnects is preferred over ball bonds.

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